MJ P-Channel Enhancement Mode Power MOSFET

Description

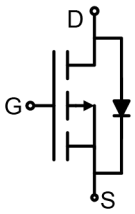
The NCE2301F uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications

General Features

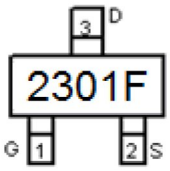
- V_{DS} =-20V,I_D =-2A
  $R_{DS(ON)}$ <150mΩ @ V_{GS} =-2.5V
  $R_{DS(ON)}$ <120mΩ @ V_{GS} =-4.5V
- High power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- PWM applications
- Load switch



Schematic diagram



Marking and pin Assignment

SOT-23 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301F	MJ2301F	SOT23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_C =25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{DS}	±12	V
Drain Current-Continuous	I_D	-2.0	A
Pulsed Drain Current (Note 1)	I_{DM}	-10	A
Maximum Power Dissipation	P_D	0.7	W
Operating Junction and Storage Temperature Range	T_J ,T_{STG}	-55 To 150	℃

Thermal Characteristic

Thermal Resistance,Junction-to-Ambient (Note 2)	$R_{\theta JA}$	178	℃/W

Electrical Characteristics (T_A =25℃unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V I_D =250μA	-20	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} =30V,V_{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I_{GSS}	V_{DS} =±12V,V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} =V_{GS} ,I_D =-250μA	-0.4	-0.7	-1	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS} =-4.5V, I_D =-2A	-	88	120	mΩ
		V_{GS} =-2.5V, I_D =-1.8A	-	120	150	mΩ
Forward Transconductance	g_{FS}	V_{DS} =-5V,I_D =-2A	4	-	-	S
Dynamic Characteristics (Note 4)						
Input Capacitance	C_{lss}	V_{DS} =-10V,V_{GS} =0V, F=1.0MHz	-	285	-	PF
Output Capacitance	C_{oss}		-	58	-	PF
Reverse Transfer Capacitance	C_{rss}		-	32	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	V_{DD} =-10V, ,R_L =5Ω V_{GS} =-4.5V,R_{GEN} =3Ω	-	9.8	-	nS
Turn-on Rise Time	t_r		-	4.9	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	20.5	-	nS
Turn-Off Fall Time	t_f		-	7	-	nS
Total Gate Charge	Q_g	V_{DS} =-10V,I_D =-2A, V_{GS} =-4.5V	-	2.9	-	nC
Gate-Source Charge	Q_{gs}		-	0.45	-	nC
Gate-Drain Charge	Q_{gd}		-	0.75	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V_{GS} =0V,I_S =-2A	-	-	-1.2	V
Diode Forward Current (Note 2)	I_S		-	-	-2.0	A

Notes:

① Repetitive Rating: Pulse width limited by maximum junction temperature.
② Surface Mounted on FR4 Board, t ≤ 10 sec.
③ Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
④ Guaranteed by design, not subject to production

Typical Electrical and Thermal Characteristics

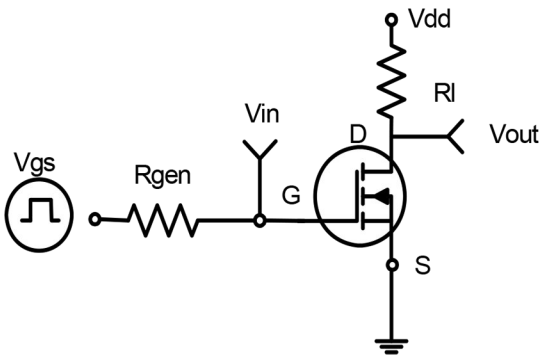


Figure 1 Switching Test Circuit

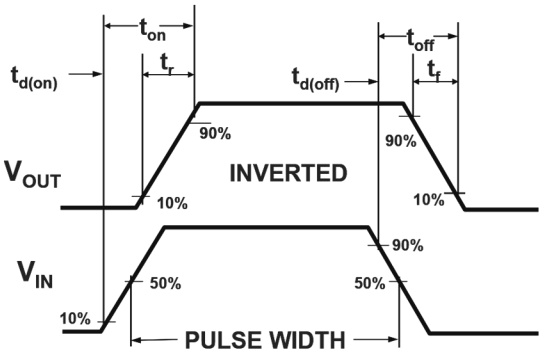


Figure 2 Switching Waveforms

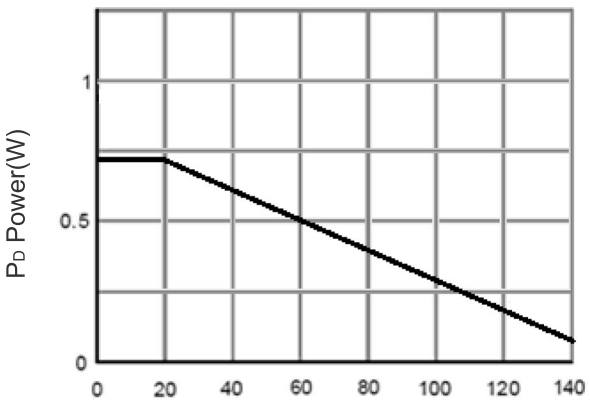


Figure 3 Power Dissipation

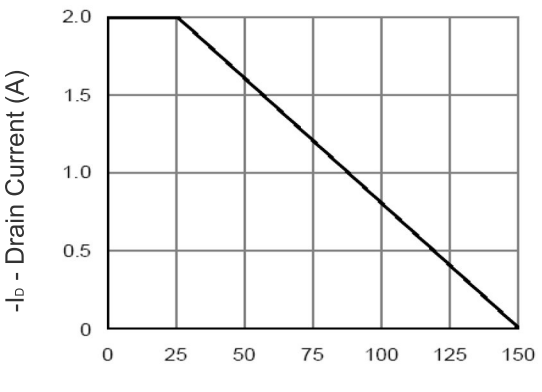


Figure 4 Drain Current

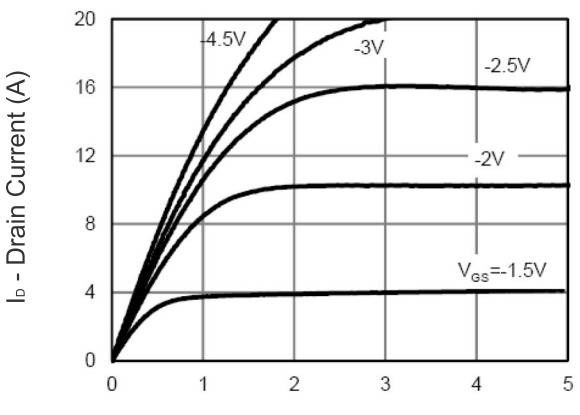


Figure 5 Output Characteristics

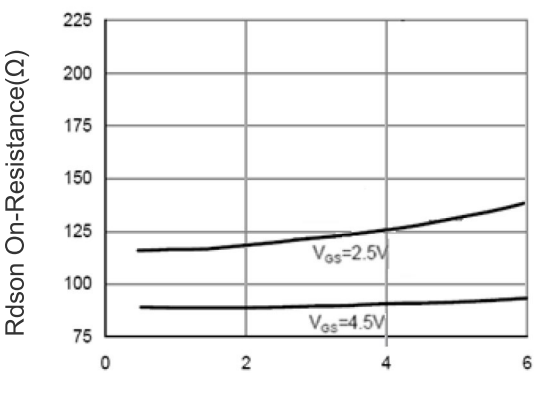


Figure 6 Drain-Source On-Resistance

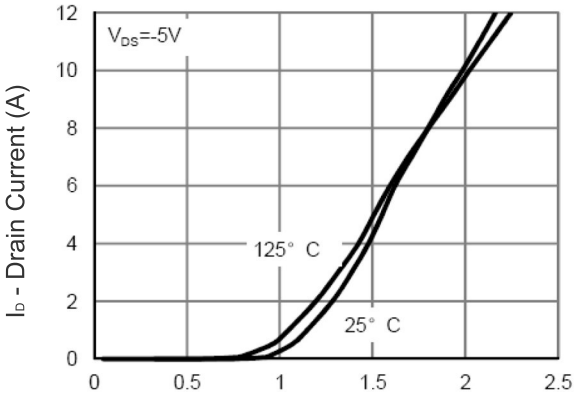


Figure 7 Transfer Characteristics

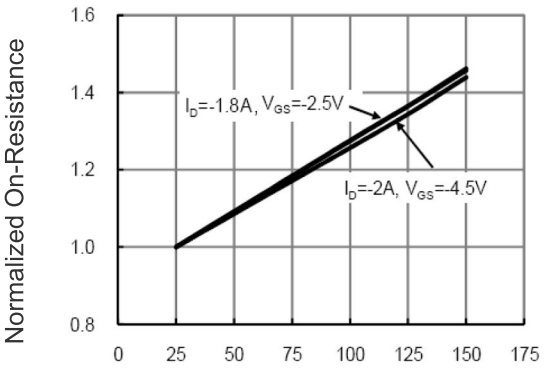


Figure 8 Drain-Source On-Resistance

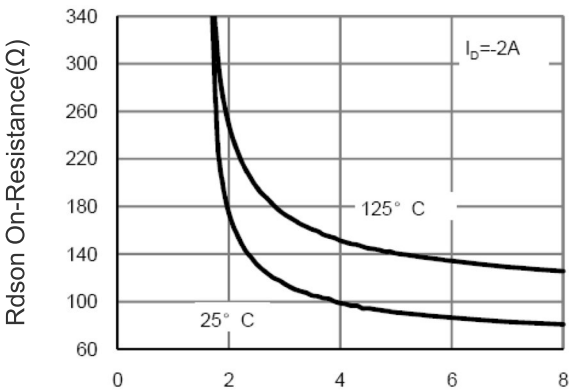


Figure 9 Rdson vs Vgs

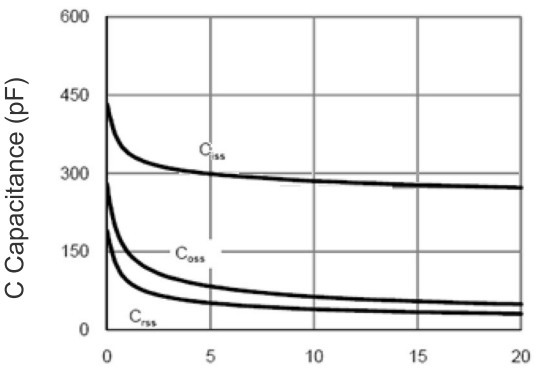


Figure 10 Capacitance vs Vds

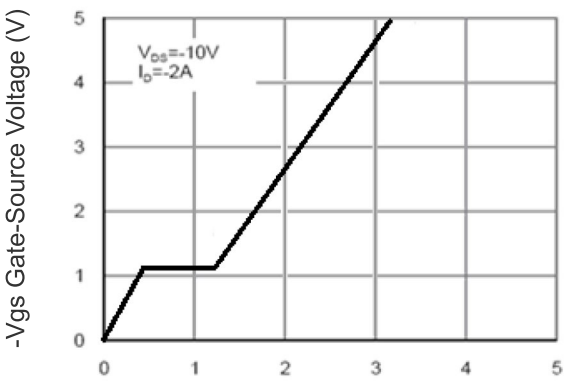


Figure 11 Gate Charge

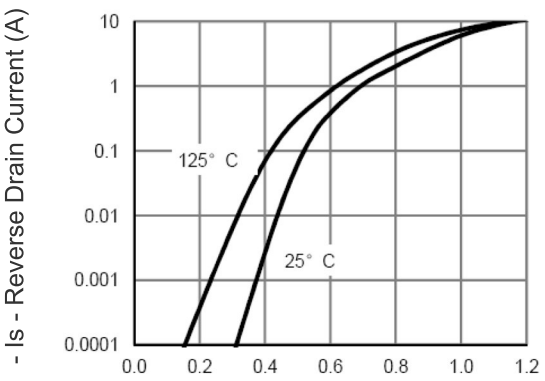


Figure 12 Source- Drain Diode Forward

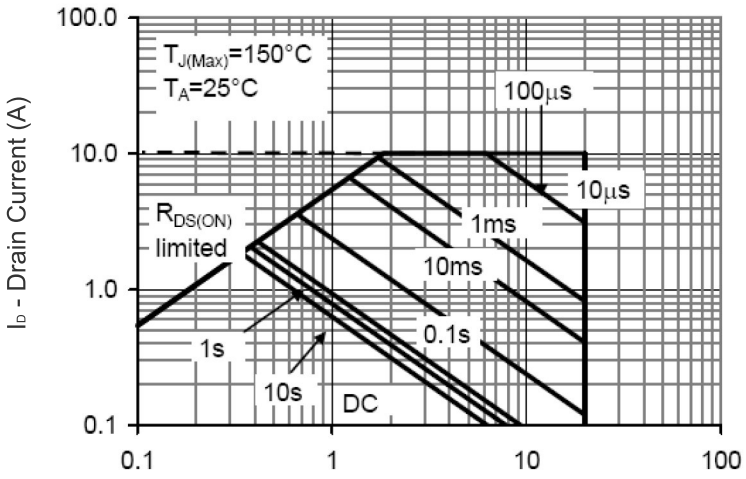


Figure 13 Safe Operation Area

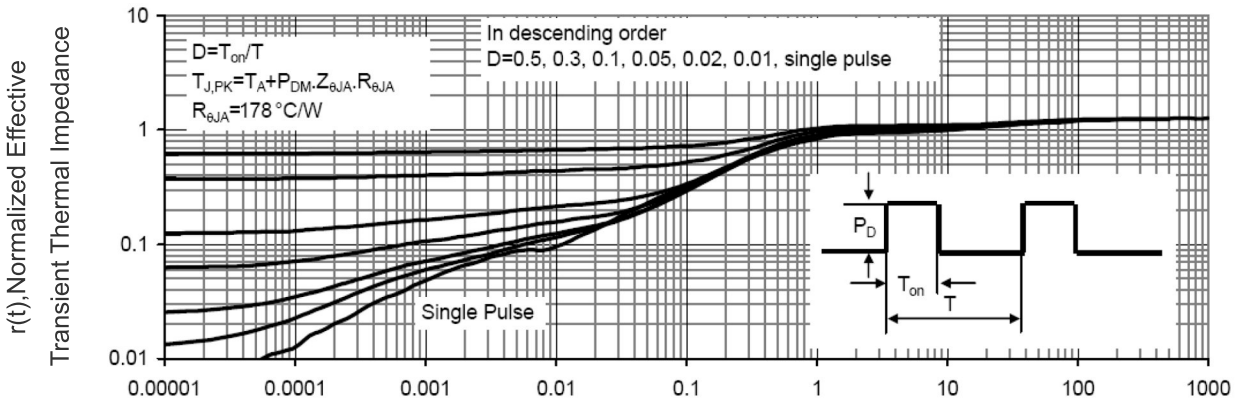
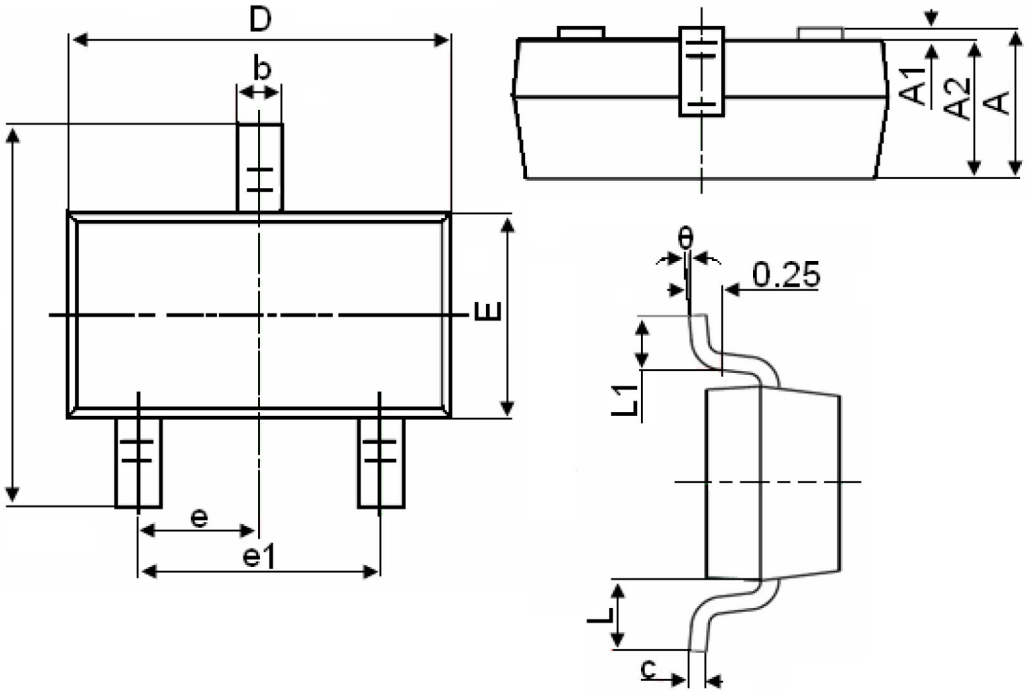


Figure 14 Normalized Maximum Transient Thermal Impedance

SOT-23 Package Information



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

Notes:

① All dimensions are in millimeters.
② Tolerance ±0.10mm (4 mil) unless otherwise specified
③ Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
④ Dimension L is measured in gauge plane.
⑤ Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

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